

HMC536LP2E

Data Sheet

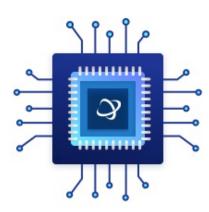
GaAs MMIC POSITIVE CONTROL T/R SWITCH, DC - 6.0 GHz

Manufacturers <u>Analog Devices, Inc</u>

Package/Case 2X2 MM

Product Type RF Switches

RoHS Pb-free Halide free



Images are for reference only

Please submit RFQ for HMC536LP2E or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

Lifecycle

The HMC536LP2(E) is a DC to 6 GHz GaAs MMIC T/R switch in leadless 2x2 mm DFN LP2 surface mount packages with an exposed ground paddle. The switch is ideal for cellular, WiMAX, & WiBro access point and subscriber applications featuring low 0.6 dB insertion loss and high +54 dBm input IP3. Power handling is excellent up through 6 GHz with the switch offering a P0.1dB compression point of +29 dBm at +3V and +33 dBm at +5V control. On-chip circuitry allows positive voltage control of 0/+3V or 0/+5V at very low DC currents. The HMC536LP2(E) occupies only 4 mm² and are ideal for applications where small size is required.

Features Application

Input P0.1dB: +33 dBm @ +5V Cellular/PCS/3G Infrastructure

Insertion Loss: 0.6 dB WiMAX, WiBro & Fixed Wireless

Positive Control: +3V or +5V CATV/CMTS

Isolation: 27 dB Test Instrumentation

2x2 mm Leadless DFNSMT Package, 4 mm²

Related Products



HMC3653LP3BE
Analog Devices, Inc
QFN-12



HMC441LP3E
Analog Devices, Inc
QFN-16



HMC253AQS24

Analog Devices, Inc 24-SSOP (0.154, 3.90mm Width)



HMC948LP3E

Analog Devices, Inc LP3



HMC358MS8GE

Analog Devices, Inc MSOP-8



HMC490

Analog Devices, Inc SMD



HMC453ST89E

Analog Devices, Inc ST89E



HMC618ALP3E

Analog Devices, Inc QFN-16